

LOW COLLECTOR SATURATION VOLTAGE
LARGE CURRENT

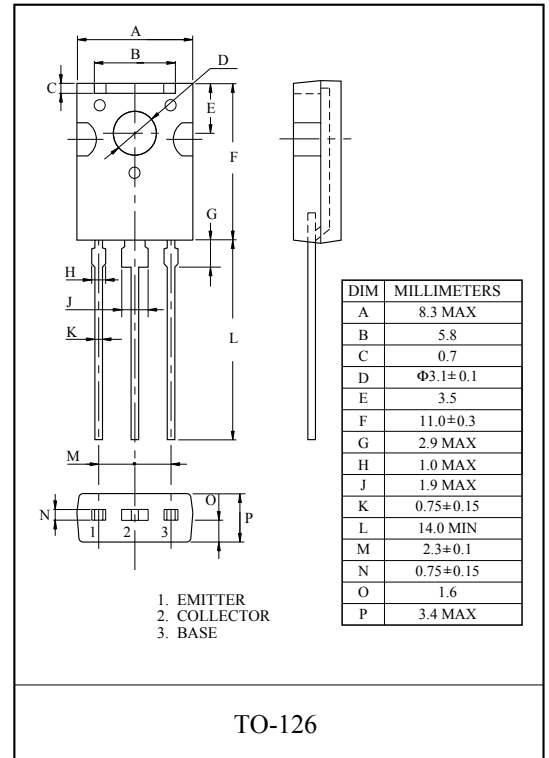
FEATURES

- High Power Dissipation : $P_C=1.5W(T_a=25^\circ C)$
- Complementary to KTD1691.

MAXIMUM RATING ($T_a=25^\circ C$)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Collector-Base Voltage		V_{CBO}	-60	V
Collector-Emitter Voltage		V_{CEO}	-60	V
Emitter-Base Voltage		V_{EBO}	-7	V
Collector Current	DC	I_C	-5	A
	Pulse *	I_{CP}	-8	
Base Current		I_B	-1	A
Collector Power Dissipation	$T_a=25^\circ C$	P_C	1.5	W
	$T_c=25^\circ C$		20	
Junction Temperature		T_j	150	$^\circ C$
Storage Temperature Range		T_{stg}	-55 ~ 150	$^\circ C$

* $PW \leq 10ms$, Duty Cycle $\leq 50\%$



ELECTRICAL CHARACTERISTICS ($T_a=25^\circ C$)

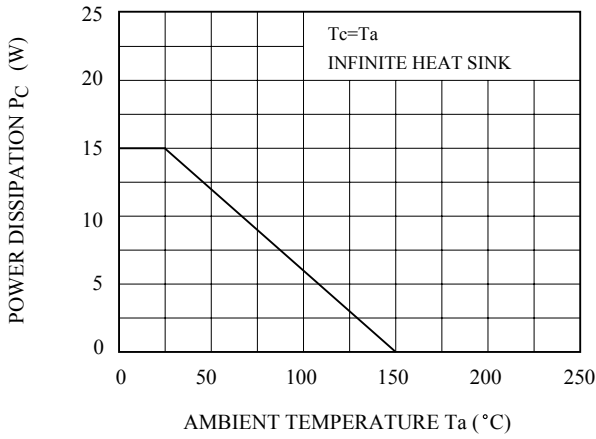
CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current		I_{CBO}	$V_{CB}=-50V, I_E=0$	-	-	-10	μA
Emitter Cut-off Current		I_{EBO}	$V_{EB}=-7V, I_C=0$	-	-	-10	μA
DC Current Gain		h_{FE1}	$V_{CE}=-1V, I_C=-0.1A$	60	-	-	
	*	h_{FE2} (Note)	$V_{CE}=-1V, I_C=-2A$	160	-	400	
		h_{FE3}	$V_{CE}=-2V, I_C=-5A$	50	-	-	
Collector-Emitter Saturation Voltage *		$V_{CE(sat)}$	$I_C=-2A, I_B=-0.2A$	-	-0.14	-0.3	V
Base-Emitter Saturation Voltage *		$V_{BE(sat)}$	$I_C=-2A, I_B=-0.2A$	-	-0.9	-1.2	V
Switching Time	Turn On Time	t_{on}		-	0.15	1	μS
	Storage Time	t_{stg}		-	0.78	2.5	
	Fall Time	t_f		-	0.18	1	

* Pulse test : $PW \leq 350\mu S$, Duty Cycle $\leq 2\%$ Pulse

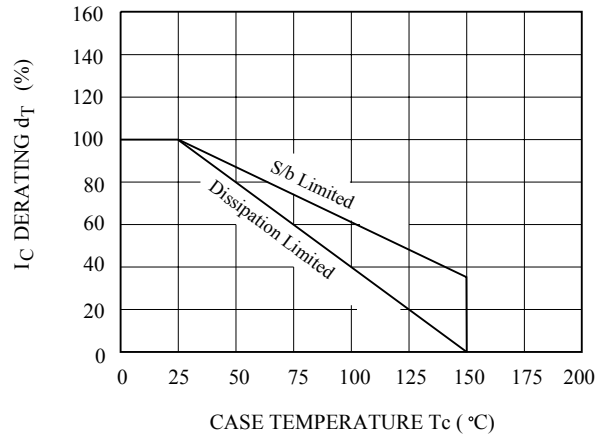
Note) $h_{FE(2)}$ Classification : O:160 ~ 320, Y:200 ~ 400.

KTB1151

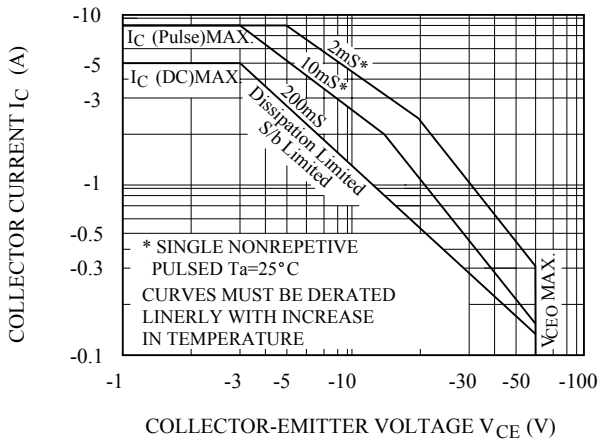
Pc - Ta



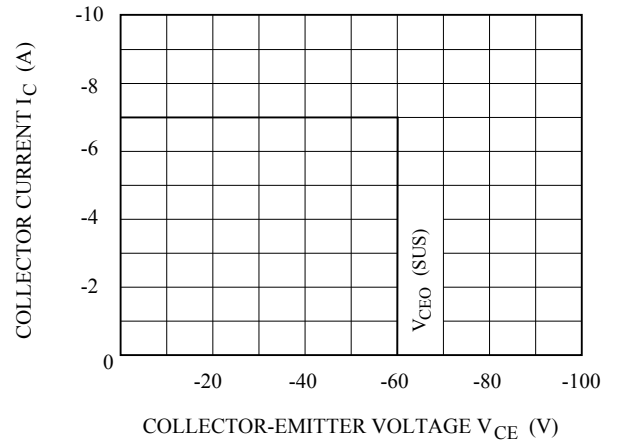
$d_T - T_C$



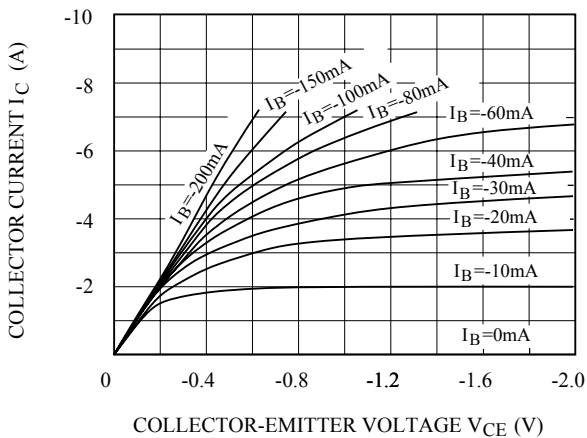
SAFE OPERATING AREA



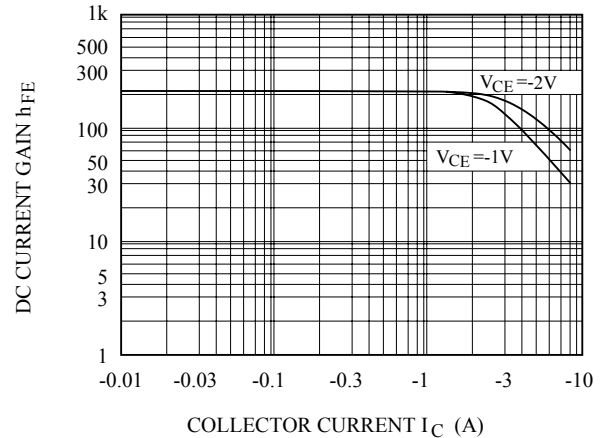
REVERSE BIAS SAFE OPERATING AREA



$I_C - V_{CE}$



$h_{FE} - I_C$



This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.